

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR

## NP22N055HLE, NP22N055ILE, NP22N055SLE

### SWITCHING

### N-CHANNEL POWER MOSFET

#### DESCRIPTION

These products are N-channel MOS Field Effect Transistors designed for high current switching applications.

#### FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance  
 $R_{DS(on)1} = 37 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 11 \text{ A)}$   
 $R_{DS(on)2} = 45 \text{ m}\Omega \text{ MAX. (} V_{GS} = 5.0 \text{ V, } I_D = 11 \text{ A)}$
- Low  $C_{iss}$  :  $C_{iss} = 730 \text{ pF TYP.}$
- Built-in gate protection diode

#### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

|  |                |             |                  |
|--|----------------|-------------|------------------|
| Drain to Source Voltage                              | $V_{DSS}$      | 55          | V                |
| Gate to Source Voltage                               | $V_{GSS}$      | $\pm 20$    | V                |
| Drain Current (DC)                                   | $I_{D(DC)}$    | $\pm 22$    | A                |
| Drain Current (Pulse) <sup>Note1</sup>               | $I_{D(pulse)}$ | $\pm 55$    | A                |
| Total Power Dissipation ( $T_A = 25^\circ\text{C}$ ) | $P_T$          | 1.2         | W                |
| Total Power Dissipation ( $T_C = 25^\circ\text{C}$ ) | $P_T$          | 45          | W                |
| Single Avalanche Current <sup>Note2</sup>            | $I_{AS}$       | 14 / 5      | A                |
| Single Avalanche Energy <sup>Note2</sup>             | $E_{AS}$       | 19 / 25     | mJ               |
| Channel Temperature                                  | $T_{ch}$       | 175         | $^\circ\text{C}$ |
| Storage Temperature                                  | $T_{stg}$      | -55 to +175 | $^\circ\text{C}$ |

**Notes** 1.  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$

2. Starting  $T_{ch} = 25^\circ\text{C}$ ,  $R_G = 25 \Omega$ ,  $V_{GS} = 20 \rightarrow 0 \text{ V}$  (See Figure 4.)

#### THERMAL RESISTANCE

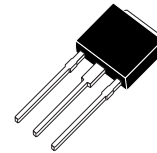
|                                       |                |      |                    |
|---------------------------------------|----------------|------|--------------------|
| Channel to Case Thermal Resistance    | $R_{th(ch-C)}$ | 3.33 | $^\circ\text{C/W}$ |
| Channel to Ambient Thermal Resistance | $R_{th(ch-A)}$ | 125  | $^\circ\text{C/W}$ |

#### ★ ORDERING INFORMATION

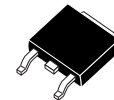
| PART NUMBER                 | PACKAGE                 |
|-----------------------------|-------------------------|
| NP22N055HLE                 | TO-251 (JEITA) / MP-3   |
| NP22N055ILE <sup>Note</sup> | TO-252 (JEITA) / MP-3Z  |
| NP22N055SLE                 | TO-252 (JEDEC) / MP-3ZK |

**Note** Not for new design.

(TO-251)



(TO-252)



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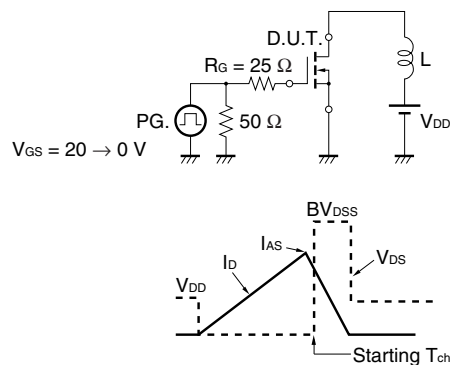
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**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)**

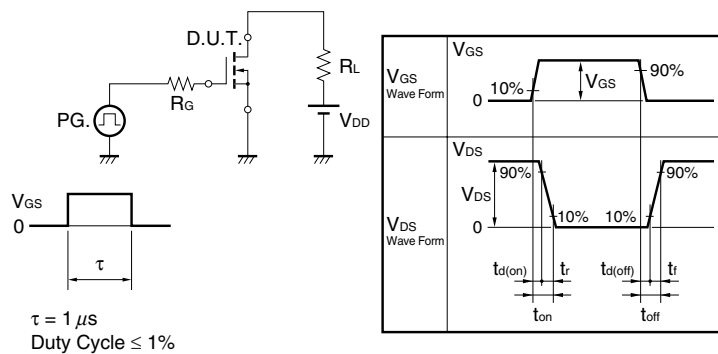
| CHARACTERISTICS                                     | SYMBOL               | TEST CONDITIONS   | MIN. | TYP. | MAX. | UNIT |
|---|----------------------|---|------|------|------|------|
| Zero Gate Voltage Drain Current                     | I <sub>DSS</sub>     | V <sub>DS</sub> = 55 V, V <sub>GS</sub> = 0 V                         |      |      | 10   | μA   |
| Gate Leakage Current                                | I <sub>GSS</sub>     | V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V                        |      |      | ±10  | μA   |
| Gate to Source Threshold Voltage                    | V <sub>GS(th)</sub>  | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA           | 1.5  | 2.0  | 2.5  | V    |
| Forward Transfer Admittance <sup>Note</sup>         | y <sub>fs</sub>      | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 11 A                         | 5    | 10   |      | S    |
| Drain to Source On-state Resistance <sup>Note</sup> | R <sub>DS(on)1</sub> | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 11 A                         |      | 29   | 37   | mΩ   |
|   | R <sub>DS(on)2</sub> | V <sub>GS</sub> = 5.0 V, I <sub>D</sub> = 11 A                        |      | 35   | 45   | mΩ   |
|   | R <sub>DS(on)3</sub> | V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 11 A                        |      | 37   | 51   | mΩ   |
| Input Capacitance                                   | C <sub>iss</sub>     | V <sub>DS</sub> = 25 V  |      | 730  | 1100 | pF   |
| Output Capacitance                                  | C <sub>oss</sub>     | V <sub>GS</sub> = 0 V   |      | 110  | 170  | pF   |
| Reverse Transfer Capacitance                        | C <sub>rss</sub>     | f = 1 MHz   |      | 52   | 95   | pF   |
| Turn-on Delay Time                                  | t <sub>d(on)</sub>   | V <sub>DD</sub> = 28 V, I <sub>D</sub> = 11 A                         |      | 9.0  | 20   | ns   |
| Rise Time   | t <sub>r</sub>       | V <sub>GS</sub> = 10 V  |      | 6.0  | 16   | ns   |
| Turn-off Delay Time                                 | t <sub>d(off)</sub>  | R <sub>G</sub> = 1 Ω  |      | 32   | 65   | ns   |
| Fall Time   | t <sub>f</sub>       |   |      | 5.4  | 14   | ns   |
| Total Gate Charge                                   | Q <sub>G1</sub>      | V <sub>DD</sub> = 44 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 22 A |      | 15   | 23   | nC   |
|   | Q <sub>G2</sub>      | V <sub>DD</sub> = 44 V  |      | 9    | 14   | nC   |
| Gate to Source Charge                               | Q <sub>GS</sub>      | V <sub>GS</sub> = 5 V   |      | 3    |      | nC   |
| Gate to Drain Charge                                | Q <sub>GD</sub>      | I <sub>D</sub> = 22 A   |      | 4.5  |      | nC   |
| Body Diode Forward Voltage <sup>Note</sup>          | V <sub>F(S-D)</sub>  | I <sub>F</sub> = 22 A, V <sub>GS</sub> = 0 V                          |      | 1.0  |      | V    |
| Reverse Recovery Time                               | t <sub>rr</sub>      | I <sub>F</sub> = 22 A, V <sub>GS</sub> = 0 V                          |      | 37   |      | ns   |
| Reverse Recovery Charge                             | Q <sub>rr</sub>      | di/dt = 100 A/μs  |      | 45   |      | nC   |

**Note** Pulsed

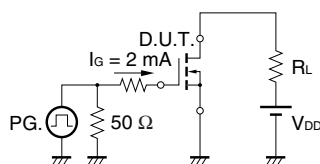
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



**TEST CIRCUIT 2 SWITCHING TIME**



**TEST CIRCUIT 3 GATE CHARGE**



TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

Figure1. DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

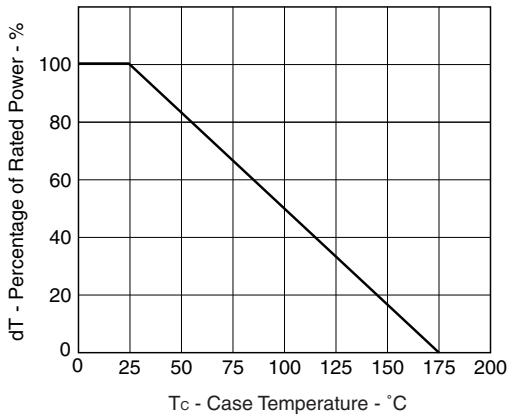


Figure2. TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

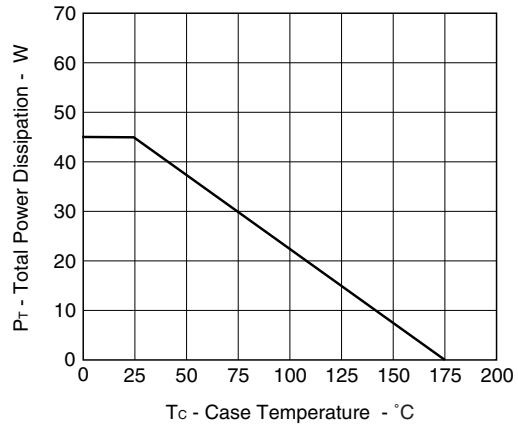


Figure3. FORWARD BIAS SAFE OPERATING AREA

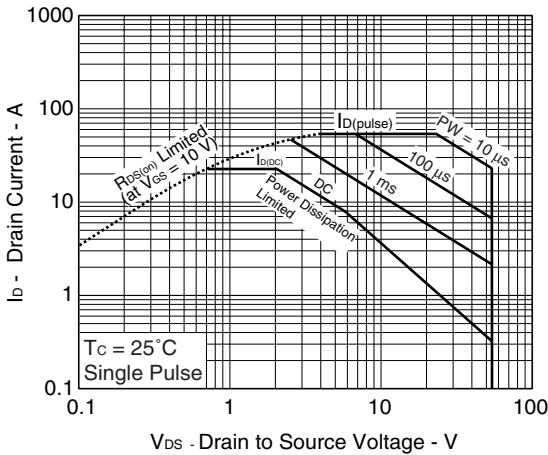


Figure4. SINGLE AVALANCHE ENERGY DERATING FACTOR

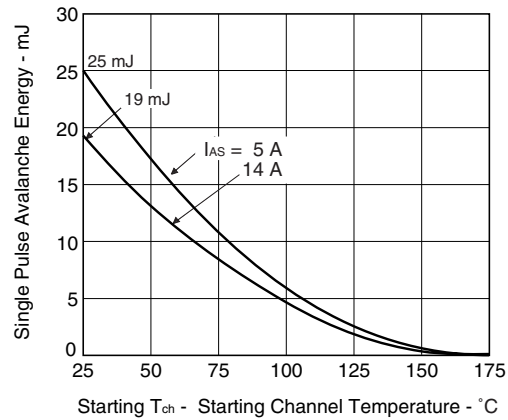


Figure5. TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

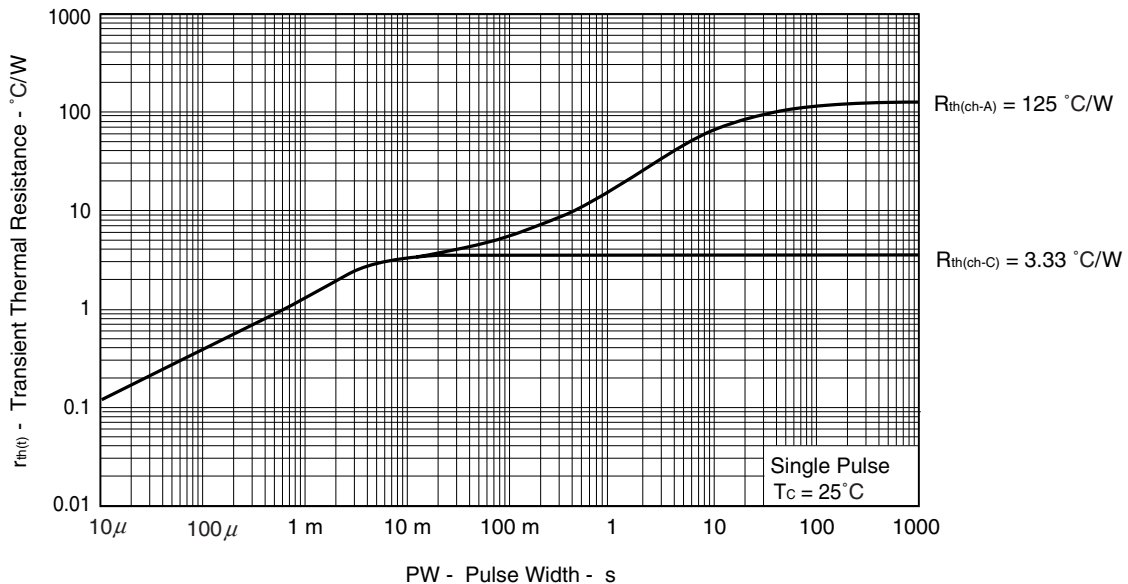


Figure6. FORWARD TRANSFER CHARACTERISTICS

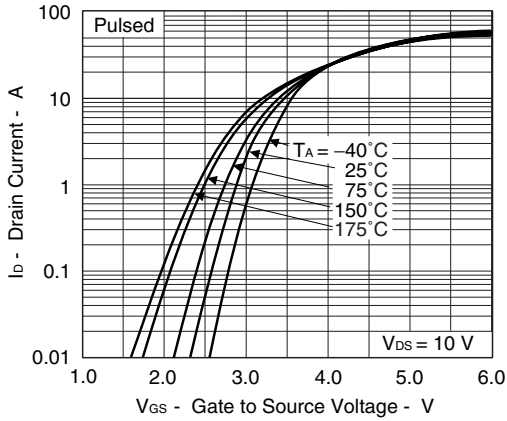


Figure7. DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

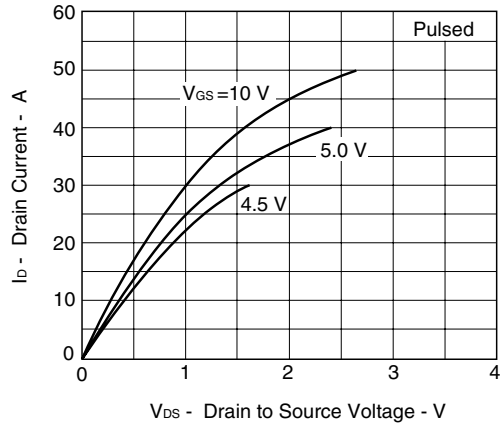


Figure8. FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

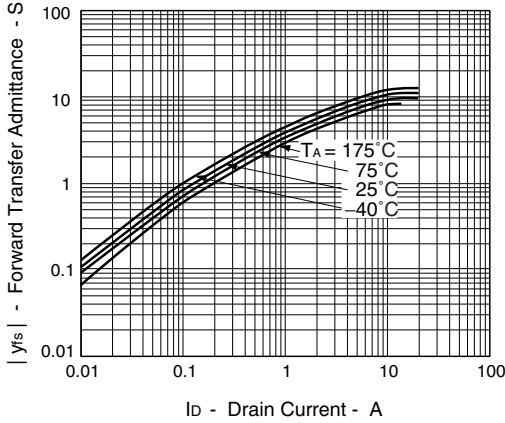


Figure9. DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

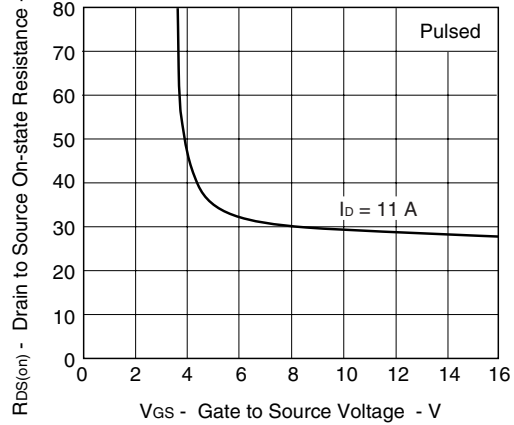


Figure10. DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

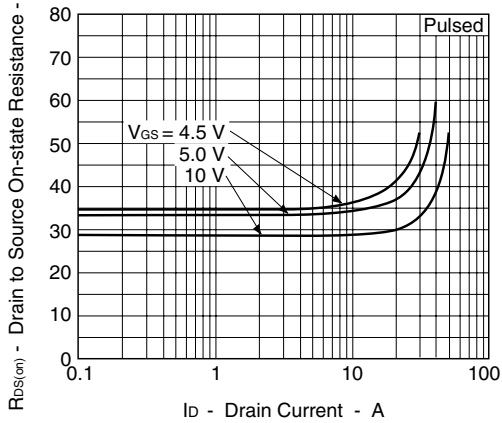


Figure11. GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE

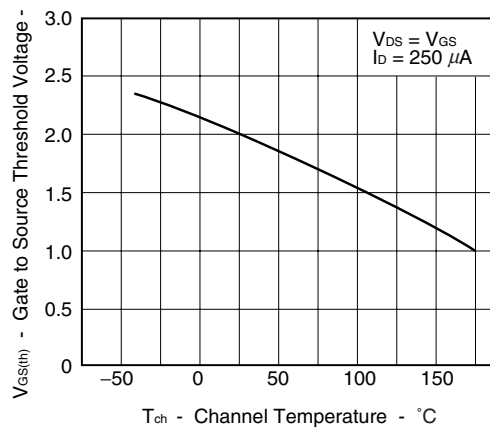


Figure12. DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

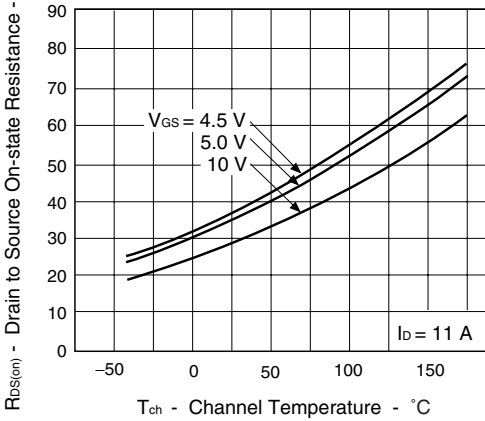


Figure13. SOURCE TO DRAIN DIODE FORWARD VOLTAGE

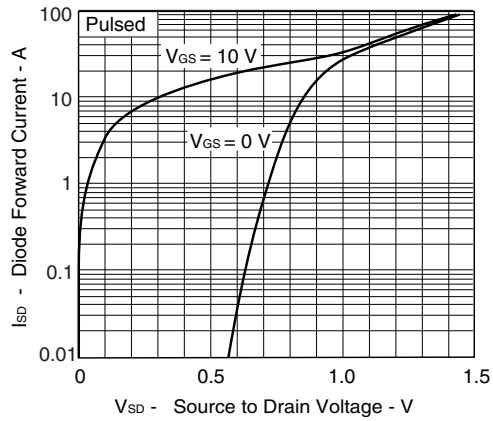


Figure14. CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

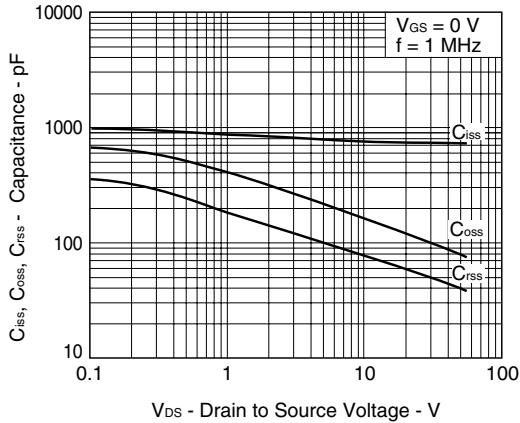


Figure15. SWITCHING CHARACTERISTICS

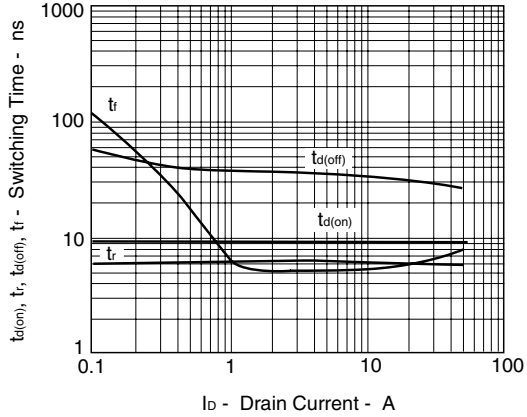


Figure16. REVERSE RECOVERY TIME vs. DRAIN CURRENT

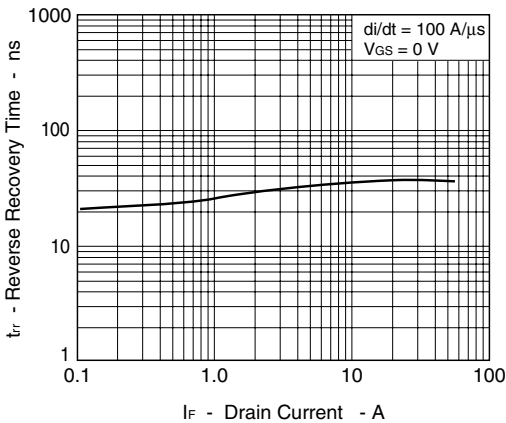
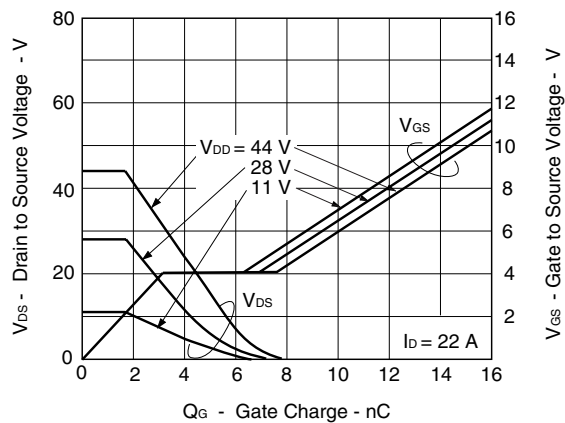
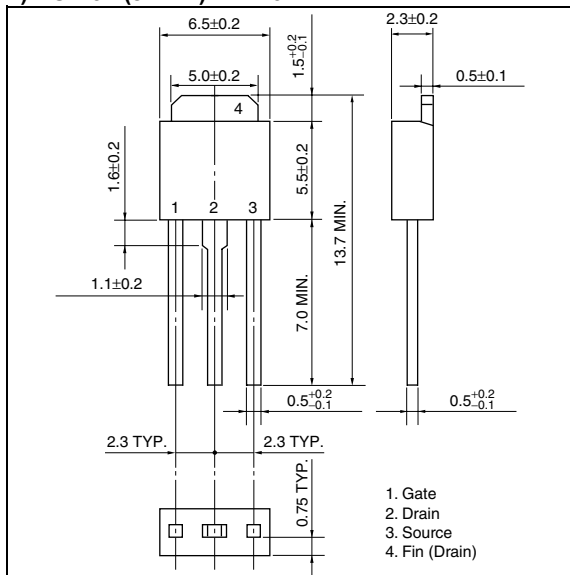


Figure17. DYNAMIC INPUT/OUTPUT CHARACTERISTICS

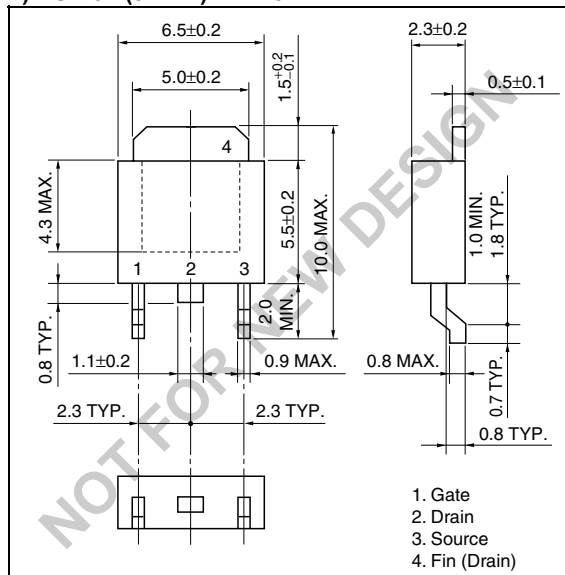


★ PACKAGE DRAWINGS (Unit: mm)

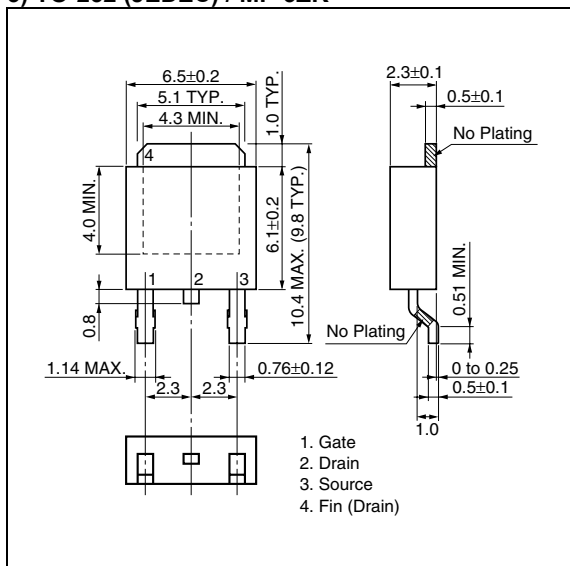
1) TO-251 (JEITA) / MP-3



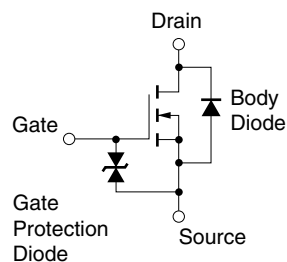
2) TO-252 (JEITA) / MP-3Z



3) TO-252 (JEDEC) / MP-3ZK



EQUIVALENT CIRCUIT



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.



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